TOSHIBA Field Effect Transistor Silicon P Channel MOS Type

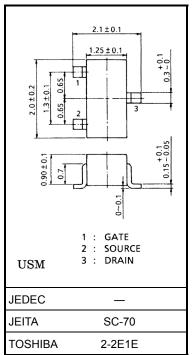
SSM3J09FU

Management Switch High Speed Switching Applications

- Small package
- Low on resistance: $R_{on} = 2.7 \Omega (max) (@V_{GS} = -10 V)$: $R_{on} = 4.2 \Omega (max) (@V_{GS} = -4 V)$

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V _{DS}	-30	V	
Gate-Source voltage		V _{GSS}	±20	V	
Drain current	DC	I _D	-200	mA	
	Pulse	I _{DP}	-400		
Drain power dissipation (Ta = 25° C)		P _D (Note 1)	150	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature		T _{stg}	-55~150	°C	



Weight: 0.006 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e.

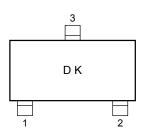
operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on FR4 board (25.4 mm \times 25.4 mm \times 1.6 t, Cu Pad: 0.6 mm 2 \times 3) Figure 1.

Marking

Equivalent Circuit (top view)



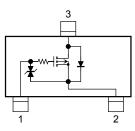
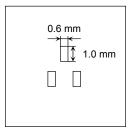


Figure 1: 25.4 mm \times 25.4 mm \times 1.6 t, Cu Pad: 0.6 mm² \times 3



Handling Precaution

When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Unit: mm

Electrical Characteristics (Ta = 25°C)

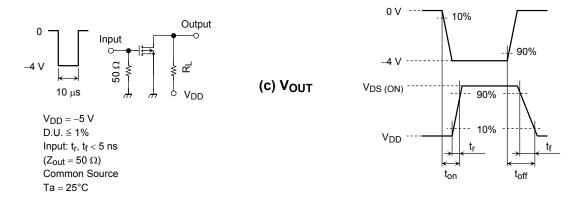
Chara	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS}=\pm 16~V,~V_{DS}=0$			±1	μΑ
Drain-Source brea	I-Source breakdown voltage $V_{(BR) DSS}$ $I_D = -1 \text{ mA}, V_{GS} = 0$		-30			V	
Drain cut-off curre	ent	I _{DSS}	$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0$			-1	μΑ
Gate threshold vo	Itage	V _{th}	$V_{DS} = -5 \text{ V}, \text{ I}_{D} = -0.1 \text{ mA}$	-1.1		-1.8	V
Forward transfer a	admittance	Y _{fs}	$V_{DS} = -5 \text{ V}, \text{ I}_{D} = -100 \text{ mA}$ (Note2)	115			mS
Drain-Source ON resistance		R _{DS (ON)}	$I_D = -100 \text{ mA}, V_{GS} = -10 \text{ V}$ (Note2)		2.1	2.7	Ω
			$I_D = -100 \text{ mA}, V_{GS} = -4 \text{ V}$ (Note2)		3.3	4.2	
			$I_D = -100 \text{ mA}, V_{GS} = -3.3 \text{ V}$ (Note2)		4.0	6.0	
Input capacitance		C _{iss}	$V_{DS}=-5~V,~V_{GS}=0,~f=1~MHz$		22	_	pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = -5 \text{ V}, V_{GS} = 0, f = 1 \text{MHz}$		5		pF
Output capacitance		C _{oss}	$V_{DS}=-5~V,~V_{GS}=0,~f=1~MHz$		14		pF
Switching time	Turn-on time	t _{on}	$V_{DD} = -5 V, I_D = -100 mA,$		85	_	ns
	Turn-off time	t _{off}	$V_{GS} = 0 \sim -4 V$	_	85	_	ns

Note 2: Pulse test

Switching Time Test Circuit

(a) Test circuit

(b) V_{IN}



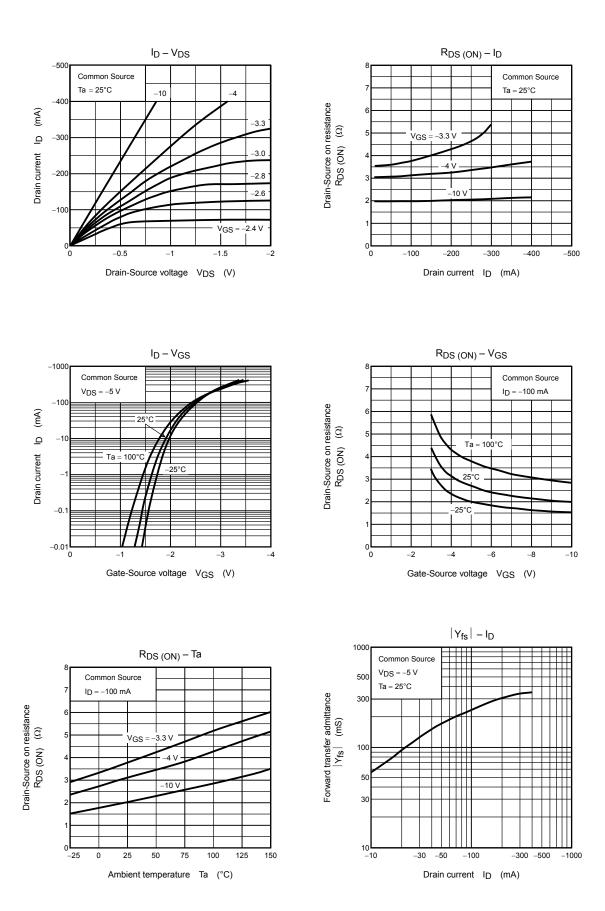
Precaution

 V_{th} can be expressed as voltage between gate and source when low operating current value is ID = $-100~\mu A$ for this product. For normal switching operation, V_{GS} (on) requires higher voltage than V_{th} and V_{GS} (off) requires lower voltage than V_{th} .

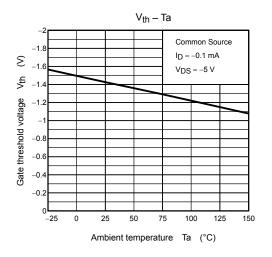
(relationship can be established as follows: V_{GS} (off) $< V_{th} < V_{GS}$ (on))

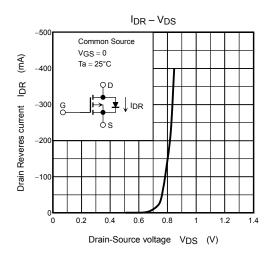
 $Please \ take \ this \ into \ consideration \ for \ using \ the \ device.$

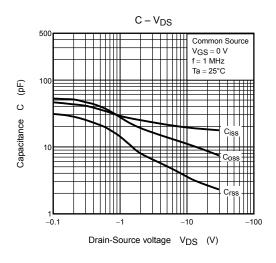
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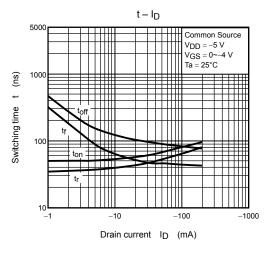


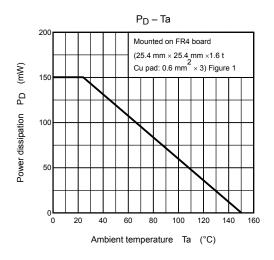
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20070701-EN GENERAL

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